

## Product Summary

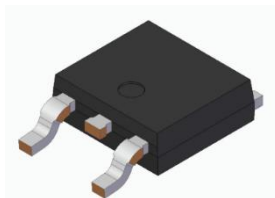
BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	Q <sub>g</sub> Typ	I <sub>D</sub> Max T <sub>C</sub> = +25°C (Note 5)
40V	3mΩ @ V <sub>GS</sub> = 10V	83nC	100A
	5mΩ @ V <sub>GS</sub> = 4.5V	35nC	100A

## Description and Applications

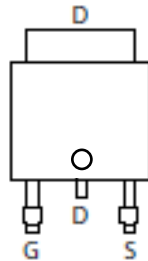
This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine-management systems
- Body control electronics
- DC-DC converters
- Motor control

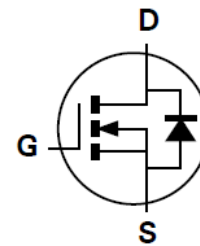
TO252 (DPAK)



Top View



Pinout Top View



Equivalent Circuit

## Features

- Rated to +175°C – Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching – Ensures More Reliable and Robust End Application
- Low R<sub>DS(ON)</sub> – Minimizes Power Losses
- Low Q<sub>g</sub> – Minimizes Switching Losses
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DMTH4004LK3Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

## Mechanical Data

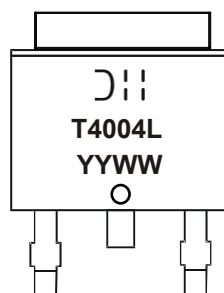
- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 Ⓔ3
- Weight: 0.33 grams (Approximate)

## Ordering Information (Note 4)

Orderable Part Number	Package	Packing	
		Qty.	Carrier
DMTH4004LK3Q-13	TO252 (DPAK)	2500	Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.
  5. Package Limited.

## Marking Information



DII = Manufacturer's Marking  
 T4004L = Product Type Marking Code  
 YYWW = Date Code Marking  
 YY = Last Two Digits of Year (ex: 26 = 2026)  
 WW = Week Code (01 to 53)

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V <sub>DSS</sub>	40	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 7) V <sub>GS</sub> = 10V	I <sub>D</sub>	100 100	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	200	A
Maximum Continuous Body Diode Forward Current (Note 7)	I <sub>S</sub>	100	A
Avalanche Current, L = 0.2mH	I <sub>AS</sub>	30	A
Avalanche Energy, L = 0.2mH	E <sub>AS</sub>	90	mJ

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6) T <sub>A</sub> = +25°C	P <sub>D</sub>	3.9	W
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>θJA</sub>	38	°C/W
Total Power Dissipation (Note 7) T <sub>C</sub> = +25°C	P <sub>D</sub>	180	W
Thermal Resistance, Junction to Case (Note 7)	R <sub>θJC</sub>	0.8	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 8)</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	40	—	—	V	V <sub>GS</sub> = 0, I <sub>D</sub> = 250µA
Zero Gate Voltage Drain Current, T <sub>J</sub> = +25°C	I <sub>DSS</sub>	—	—	1	µA	V <sub>DS</sub> = 32V, V <sub>GS</sub> = 0
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0
<b>ON CHARACTERISTICS (Note 8)</b>						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	—	3	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250µA
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	2.4	3	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 50A
		—	4	5	mΩ	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 50A
Diode Forward Voltage	V <sub>SD</sub>	—	0.7	1.2	V	V <sub>GS</sub> = 0, I <sub>S</sub> = 50A
<b>DYNAMIC CHARACTERISTICS (Note 9)</b>						
Input Capacitance	C <sub>iss</sub>	—	4450	—	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0, f = 1MHz
Output Capacitance	C <sub>oss</sub>	—	1407	—	pF	
Reverse Transfer Capacitance	C <sub>rss</sub>	—	74	—	pF	
Gate Resistance	R <sub>g</sub>	—	0.7	—	Ω	V <sub>DS</sub> = 0, V <sub>GS</sub> = 0, f = 1MHz
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Q <sub>g</sub>	—	35	—	nC	V <sub>DS</sub> = 20V, I <sub>D</sub> = 30A
Total Gate Charge (V <sub>GS</sub> = 10V)	Q <sub>g</sub>	—	83	—	nC	
Gate-Source Charge	Q <sub>gs</sub>	—	10	—	nC	
Gate-Drain Charge	Q <sub>gd</sub>	—	11.2	—	nC	
Turn-On Delay Time	t <sub>d(ON)</sub>	—	5.9	—	ns	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 20V, R <sub>G</sub> = 1.6Ω, I <sub>D</sub> = 30A
Turn-On Rise Time	t <sub>r</sub>	—	13.2	—	ns	
Turn-Off Delay Time	t <sub>d(OFF)</sub>	—	25.8	—	ns	
Turn-Off Fall Time	t <sub>f</sub>	—	7.9	—	ns	
Body Diode Reverse-Recovery Time	t <sub>RR</sub>	—	48	—	ns	I <sub>F</sub> = 50A, di/dt = 100A/µs
Body Diode Reverse-Recovery Charge	Q <sub>RR</sub>	—	72	—	nC	I <sub>F</sub> = 50A, di/dt = 100A/µs

- Notes:
- Package Limited.
  - Device mounted with exposed drain pad on 25mm by 25mm 2oz copper on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions while operating in a steady state.
  - Thermal resistance from junction to solder point (on the exposed drain pin).
  - Short duration pulse test used to minimize self-heating effect.
  - Guaranteed by design. Not subject to product testing.

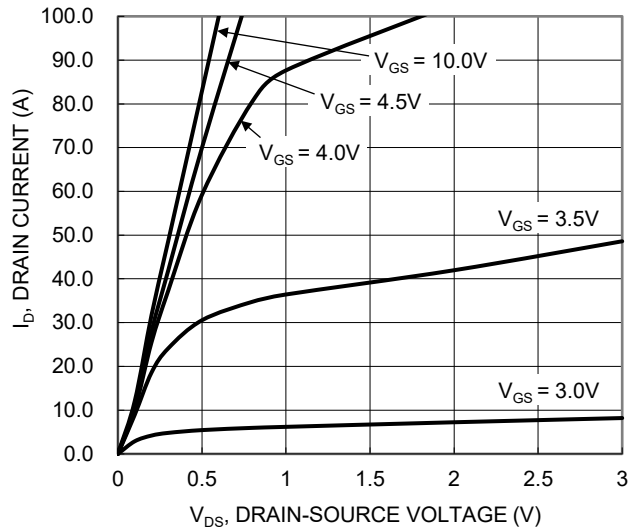


Figure 1. Typical Output Characteristic

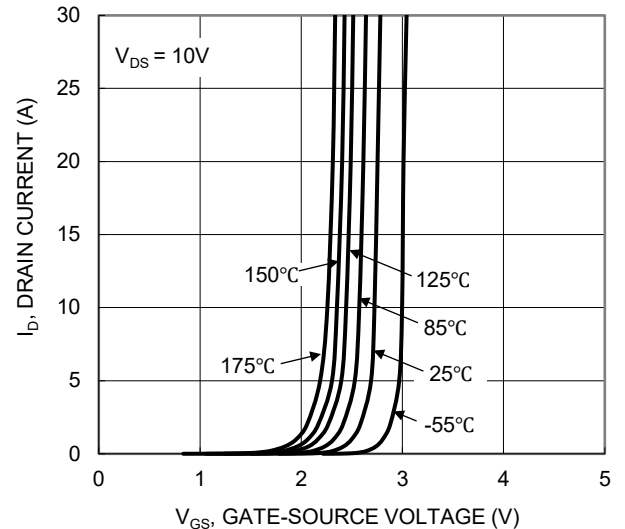


Figure 2. Typical Transfer Characteristic

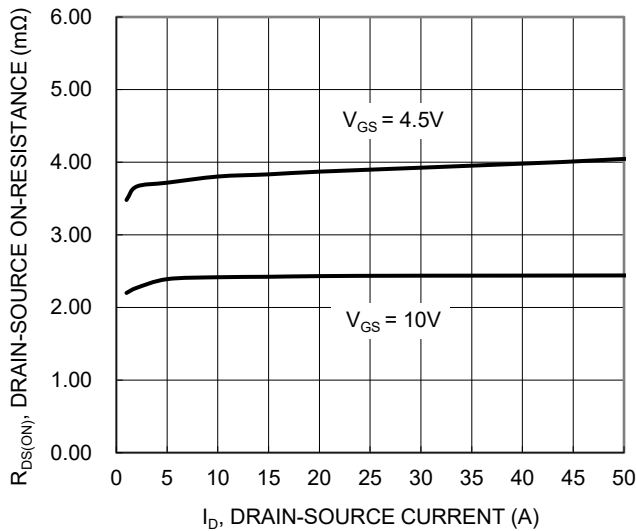


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

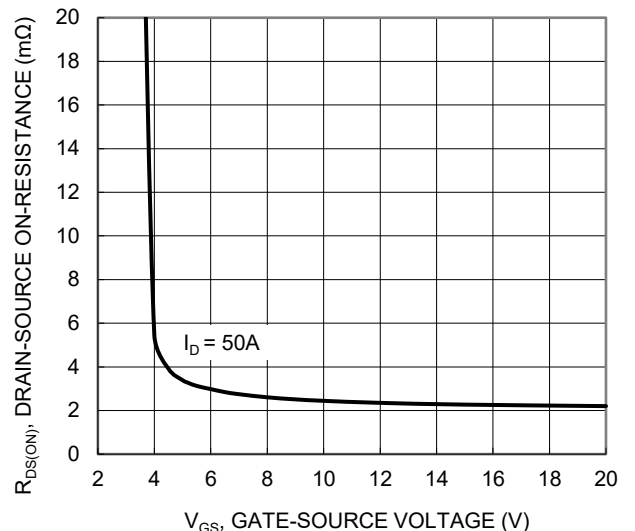


Figure 4. Typical Transfer Characteristic

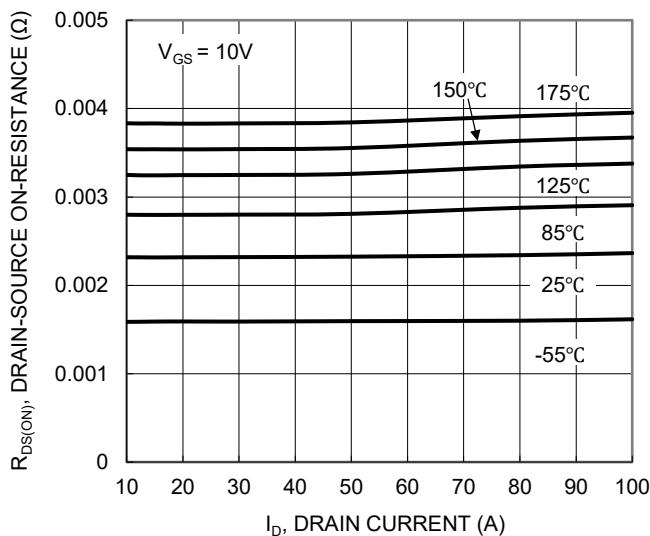


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

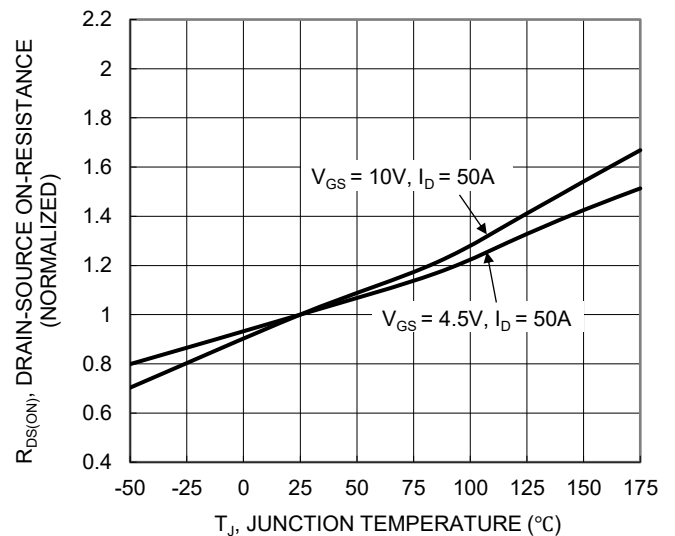
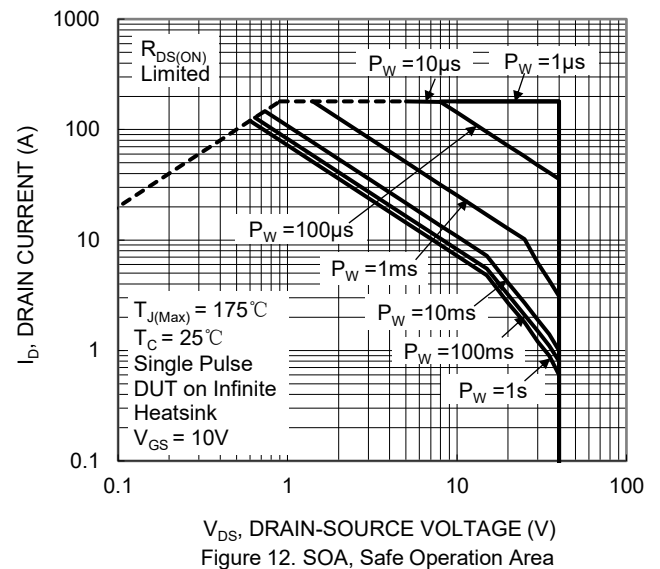
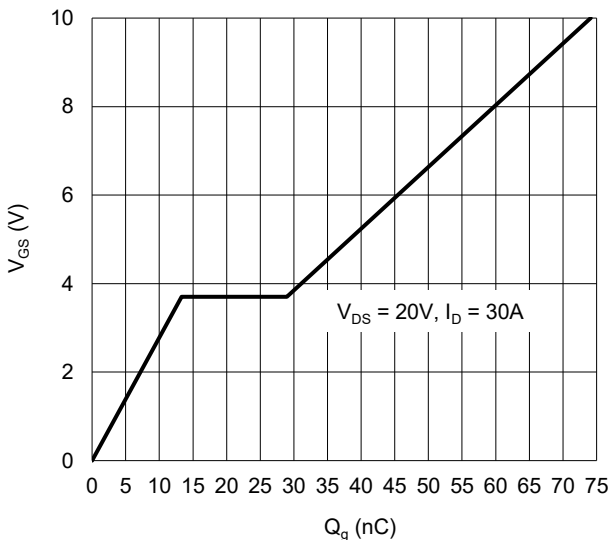
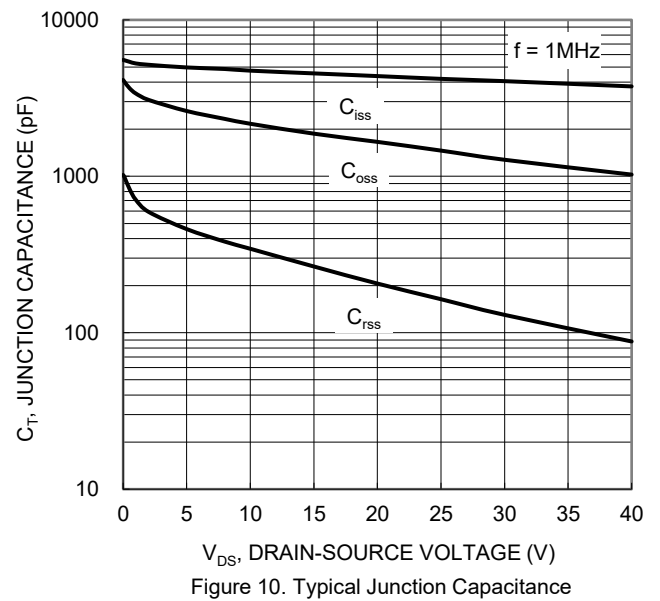
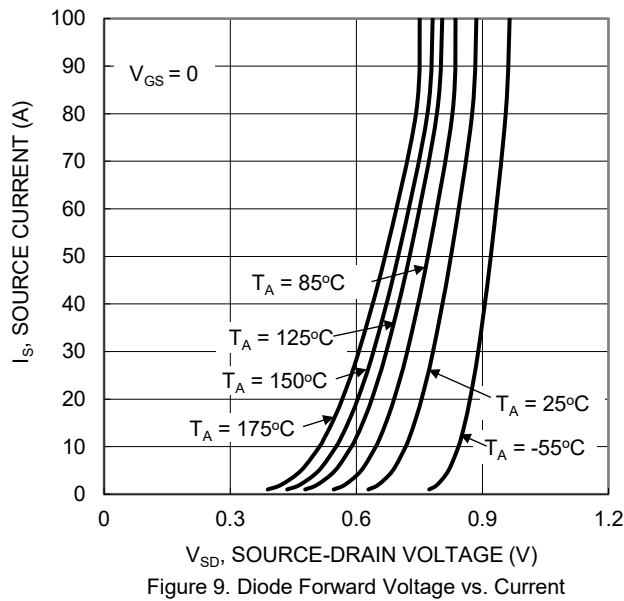
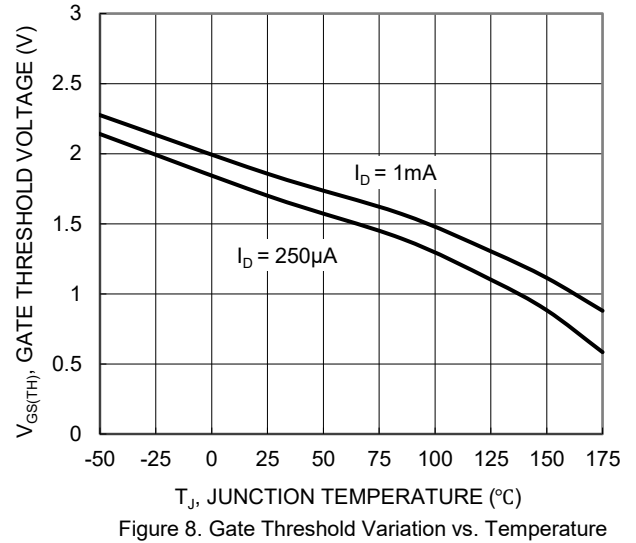
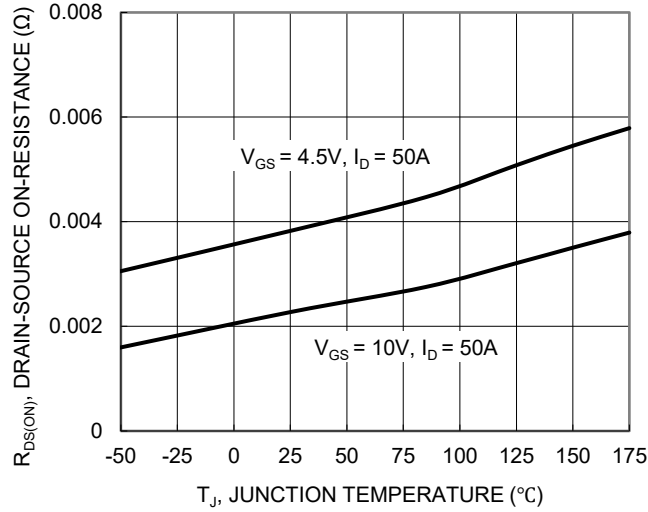


Figure 6. On-Resistance Variation with Temperature



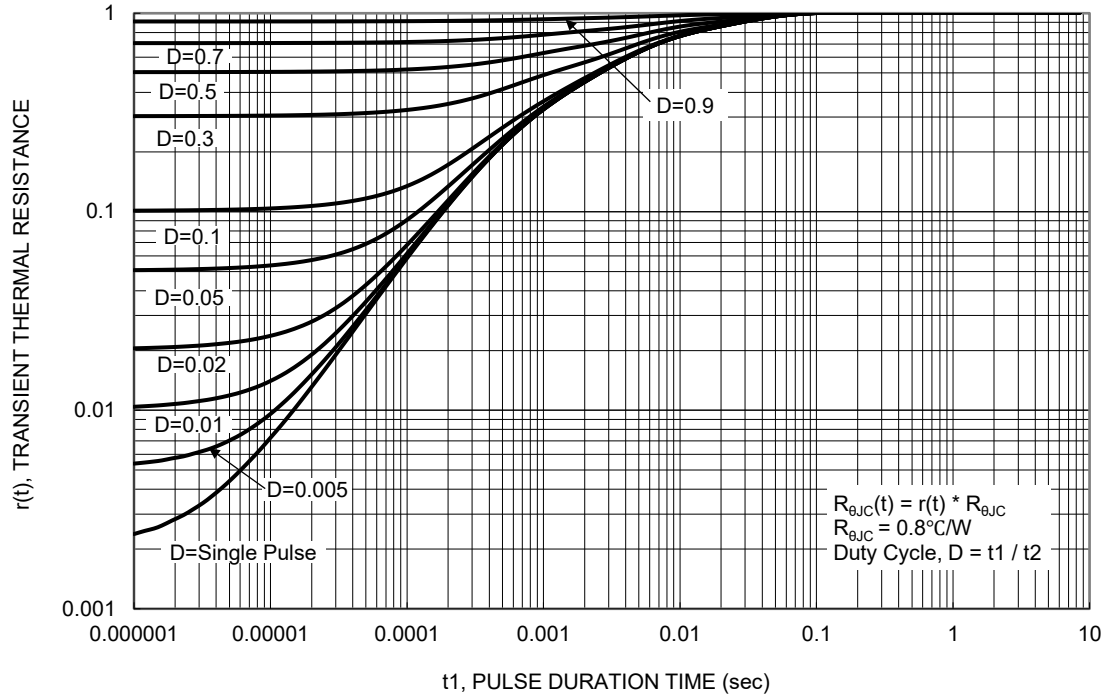
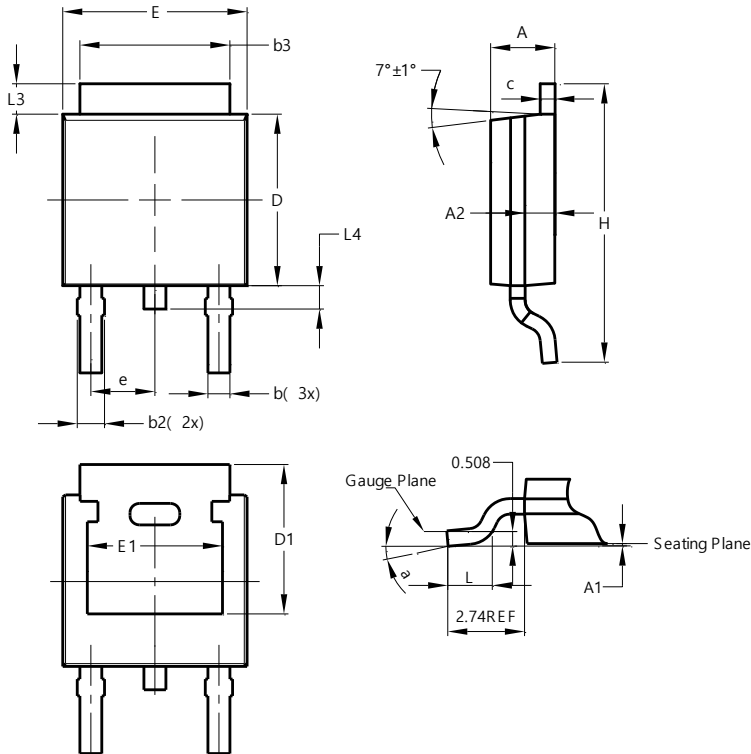


Figure 13. Transient Thermal Resistance

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### TO252 (DPAK)

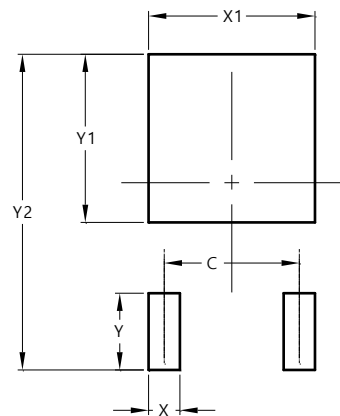


TO252 (DPAK)			
Dim	Min	Max	Typ
A	2.19	2.39	2.29
A1	0.00	0.13	0.08
A2	0.97	1.17	1.07
b	0.64	0.88	0.783
b2	0.76	1.14	0.95
b3	5.21	5.50	5.33
c	0.45	0.58	0.531
D	6.00	6.20	6.10
D1	5.21	--	--
e	2.286 BSC		
E	6.45	6.70	6.58
E1	4.32	--	--
H	9.40	10.41	9.91
L	1.40	1.78	1.59
L3	0.88	1.27	1.08
L4	0.64	1.02	0.83
a	0°	10°	--
All Dimensions in mm			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### TO252 (DPAK)



Dimensions	Value (in mm)
C	4.572
X	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

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